



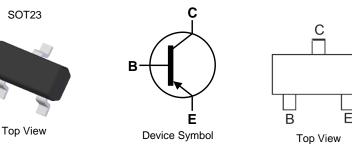
#### PNP SMALL SIGNAL TRANSISTOR IN SOT23

#### Features

- Ideally Suited for Automatic Insertion
- Complementary NPN Types: BC846 BC848
- For Switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (£3)
- Weight: 0.008 grams (Approximate)



## Pin-Out

#### Ordering Information (Notes 4 & 5)

| Product      | Compliance | Marking | Reel Size<br>(inches) | Quantity<br>per Reel | Product     | Compliance | Marking | Reel Size<br>(inches) | Quantity<br>per Reel |
|--------------|------------|---------|-----------------------|----------------------|-------------|------------|---------|-----------------------|----------------------|
| BC856A-7-F   | AEC-Q101   | K3A     | 7                     | 3,000                | BC857B-7-F  | AEC-Q101   | K3B     | 7                     | 3,000                |
| BC856AQ-7-F  | Automotive | K3A     | 7                     | 3,000                | BC857BQ-7-F | Automotive | K3B     | 7                     | 3,000                |
| BC856B-7-F   | AEC-Q101   | K3B     | 7                     | 3,000                | BC857B-13-F | AEC-Q101   | K3B     | 13                    | 10,000               |
| BC856BQ-7-F  | Automotive | K3B     | 7                     | 3,000                | BC857C-7-F  | AEC-Q101   | K3G     | 7                     | 3,000                |
| BC856B-13-F  | AEC-Q101   | K3B     | 13                    | 10,000               | BC857C-13-F | AEC-Q101   | K3G     | 13                    | 10,000               |
| BC856BQ-13-F | Automotive | K3B     | 13                    | 10,000               | BC858A-7-F  | AEC-Q101   | K3A     | 7                     | 3,000                |
| BC857A-7-F   | AEC-Q101   | K3A     | 7                     | 3,000                | BC858B-7-F  | AEC-Q101   | K3B     | 7                     | 3,000                |
|              |            |         |                       |                      | BC858C-7-F  | AEC-Q101   | K3G     | 7                     | 3,000                |

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

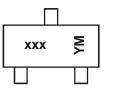
2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.

3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.

5. Tape width is 8mm. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### **Marking Information**



xxx = Product Type Marking Code (Please see Ordering Information) YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: A = 2013)

M or  $\overline{M}$  = Month (ex: 9 = September)

| Date Code Key |      |     |       |      |      |      |      |     |      |      |     |      |
|---------------|------|-----|-------|------|------|------|------|-----|------|------|-----|------|
| Year          | 2010 | 20  | 011   | 2012 | 2    | 2013 | 2014 |     | 2015 | 2016 |     | 2017 |
| Code          | Х    |     | Y     | Z    | A    |      | В    |     | С    | D    |     | E    |
| Month         | Jan  | Feb | Mar   | Apr  | May  | Jun  | Jul  | Aug | Sep  | Oct  | Nov | Dec  |
| Month         | Uan  | 100 | Intal |      | wiay | oun  | oui  |     |      |      |     |      |
| Code          | 1    | 2   | 3     | 4    | 5    | 6    | 7    | 8   | 9    | 0    | N   | D    |



### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteris                  | tic   | Symbol           | Value | Unit |
|------------------------------|-------|------------------|-------|------|
|                              | BC856 |                  | -80   |      |
| Collector-Base Voltage       | BC857 | V <sub>CBO</sub> | -50   | V    |
|                              | BC858 |                  | -30   |      |
|                              | BC856 |                  | -65   |      |
| Collector-Emitter Voltage    | BC857 | V <sub>CEO</sub> | -45   | V    |
|                              | BC858 |                  | -30   |      |
| Emitter-Base Voltage         |       | V <sub>EBO</sub> | -5.0  | V    |
| Continuous Collector Current |       | lc               | -100  | mA   |
| Peak Collector Current       |       | I <sub>CM</sub>  | -200  | mA   |
| Peak Emitter Current         |       | I <sub>EM</sub>  | -200  | mA   |
| Peak Base Current            |       | I <sub>BM</sub>  | -200  | mA   |

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                                 |                                  | Symbol           | Value | Unit  |
|--|----------------------------------|------------------|-------|-------|
| Power Dissipation                              | (Note 6)                         | P                | 310   | mW    |
|  | (Note 7)                         | P <sub>D</sub>   | 350   | TTIVV |
| Thermal Desistance Junction to Ambient         | (Note 6)                         |                  | 403   | °C/W  |
| Thermal Resistance, Junction to Ambient        | (Note 7)                         | R <sub>0JA</sub> | 357   | C/VV  |
| Thermal Resistance, Junction to Leads (Note 8) |                                  | R <sub>θJL</sub> | 350   | °C/W  |
| Operating and Storage Temperature Range        | T <sub>J</sub> ,T <sub>STG</sub> | -65 to +150      | °C    |       |

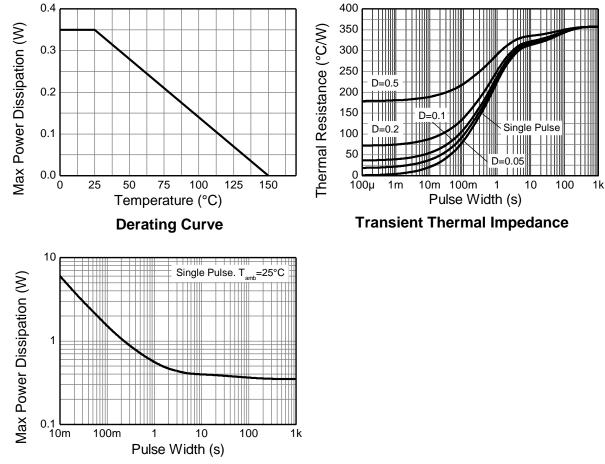
### ESD Ratings (Note 9)

| Characteristic                             | Symbol  | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V    | ЗA          |
| Electrostatic Discharge - Machine Model    | ESD MM  | 400   | V    | С           |

6. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air Notes: For a device mounted on minimum recommended pad layout 102 copper that is conditions whilst operating in a steady-state.
Same as Note 6, except the device is mounted on 15 mm x 15mm 1oz copper.
Thermal resistance from junction to solder-point (at the end of the leads).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**



**Pulse Power Dissipation** 



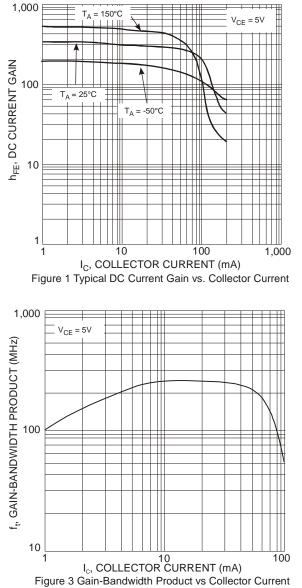
## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

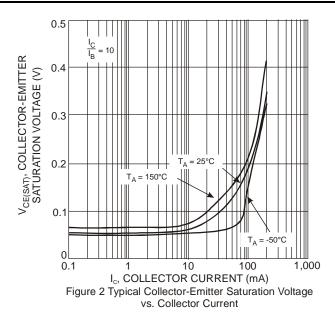
| Ch  | aracteristic   |                                    | Symbol               | Min        | Тур                  | Max        | Unit   | Test Condition  |  |
|---|--|------------------------------------|----------------------|------------|----------------------|------------|--|---|--|
|   |  | BC856                              |                      | -80        |                      |            |  |   |  |
| Collector-Base Breakdown V                | 'oltage  | BC857                              | <b>BV</b> CBO        | -50        | —                    | —          | V  | I <sub>C</sub> = -10μA  |  |
|   |  | BC858                              |                      | -30        |                      |            |  |   |  |
| Collector-Emitter Breakdown               | Voltage  | BC856                              | -65                  |            |                      |            |  |   |  |
| (Note 10)                                 | vollage  | BC857                              | BV <sub>CEO</sub>    | -45        | —                    | —          | V  | $I_{\rm C} = -10 {\rm mA}$  |  |
| · · · ·                                   |  | BC858                              |                      | -30        |                      |            |  |   |  |
| Emitter-Base Breakdown Vo                 | ltage  |                                    | BVEBO                | -5         | —                    | _          | V  | $I_E = -1\mu A$   |  |
| Collector Cutoff Current                  |  |                                    | long                 | _          | _                    | -15        | nA   | V <sub>CB</sub> = -30V  |  |
| Collector Catoli Carrent                  |  |                                    | I <sub>CBO</sub>     |            |                      | -4         | μA   | $V_{CB} = -30V, T_{J} = +150^{\circ}C$  |  |
|   |  | BC856                              |                      |            |                      | -15        |  | V <sub>CE</sub> = -80V  |  |
| Collector Emitter Cutoff Curr             | ent  | BC857                              | ICES                 | _          | _                    | -15        | nA   | V <sub>CE</sub> = -50V  |  |
|   |  | BC858                              | <u> </u>             |            |                      | -15        |  | $V_{CE} = -30V$   |  |
| Emitter-Base Cutoff Current               |  |                                    | I <sub>EBO</sub>     | -          | _                    | -100       | nA   | $V_{EB} = -5V$  |  |
|   | BC856A / E   | 3C857A / BC858A                    | LDO                  | _          | 200                  |            |  |   |  |
| Small Signal Current Gain                 |  | 3C857B / BC858B                    | h <sub>fe</sub>      |            | 330                  | _          | —  |   |  |
| (Note 10)                                 | BC857  | 7C / BC858C                        |                      |            | 600                  |            |  |   |  |
|   | BC856A / E   | BC857A / BC858A                    | h <sub>ie</sub>      |            | 2.7                  |            |  |   |  |
| Input Impedance (Note 10)                 |  | 3C857B / BC858B                    |                      |            | 4.5                  | —          | kΩ   |   |  |
|   | BC857C / BC858C                                      |                                    |                      |            | 8.7                  |            |  | $I_{C} = -2.0 \text{mA}, V_{CE} = -5 \text{V}$  |  |
| Output Admittance                         | BC856A / BC857A / BC858A<br>BC856B / BC857B / BC858B |                                    | h <sub>oe</sub>      | —          | 18                   |            | μS   | f = 1.0kHz  |  |
| (Note 10)                                 |  |                                    |                      |            | 30                   | - 1        |  |   |  |
| (   |  | 7C / BC858C                        |                      |            | 60                   |            |  | 4   |  |
| Reverse Voltage Transfer                  |  | 8C857A / BC858A                    |                      | _          | 1.5x10 <sup>-4</sup> |            |  |   |  |
| Ratio (Note 10)                           |  | C857B / BC858B                     | h <sub>re</sub>      |            | $2x10^{-4}$          | _          | _  |   |  |
| , ,,                                      |  | 7C / BC858C                        |                      | 405        | 3x10 <sup>-4</sup>   | 050        |  |   |  |
| DC Current Coin (Note 10)                 |  | BC857A / BC858A<br>BC857B / BC858B |                      | 125        | 180<br>290           | 250        |  | $I_{C} = -2.0 \text{mA}, V_{CE} = -5 \text{V}$  |  |
| DC Current Gain (Note 10)                 |  | C / BC858C                         | h <sub>FE</sub>      | 220<br>420 | 290<br>520           | 475<br>800 | _  |   |  |
|   | DC031  | C / DC030C                         |                      | 420        | -75                  | -300       |  |   |  |
| Collector-Emitter Saturation              | Voltage (Note 10                                     | D)                                 | V <sub>CE(sat)</sub> | _          | -250                 | -650       | mV   | $I_{\rm C} = -10$ mA, $I_{\rm B} = -0.5$ mA   |  |
|   |  |                                    | . ,                  | 000        |                      |            |  | $I_{\rm C} = -100 {\rm mA}, I_{\rm B} = -5.0 {\rm mA}$  |  |
| Base-Emitter Turn-On Voltag               | ge (Note 10)   |                                    | V <sub>BE(on)</sub>  | -600       | -650                 | -750       | mV   | $I_C = -2mA$ , $V_{CE} = -5V$   |  |
|   |  |                                    | 52(01)               | _          | —                    | -820       |  | $I_{\rm C} = -10 {\rm mA}, V_{\rm CE} = -5 {\rm V}$   |  |
| Base-Emitter Saturation Voltage (Note 10) |  | V <sub>BE(sat)</sub>               | _                    | -700       |                      | mV         | $I_{C} = -10 \text{mA}, I_{B} = -0.5 \text{mA}$      |   |  |
|   |  | · ,                                |                      | -850       | -1100                |            | $I_{\rm C} = -100 {\rm mA}, I_{\rm B} = -5 {\rm mA}$ |   |  |
| Output Capacitance                        |  |                                    | Cobo                 | —          | 3                    | —          | pF   | $V_{CB} = -10V, f = 1.0MHz$   |  |
| Transition Frequency                      |  | f⊤                                 | 100                  | 200        |                      | MHz        | $V_{CE} = -5V, I_C = -10mA, f = 100MHz$              |   |  |
| Noise Figure                              |  |                                    | NF                   | _          | 2                    | 10         | dB   | $\label{eq:VCE} \begin{array}{l} V_{CE} = \text{-}5V, \ I_C = \text{-}200\muA \\ R_S = 2k\Omega, \ f = 1kHz \\ \Deltaf = 200Hz \end{array}$ |  |

Note: 10. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

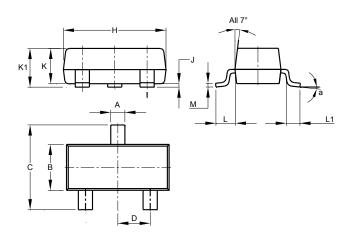






## **Package Outline Dimensions**

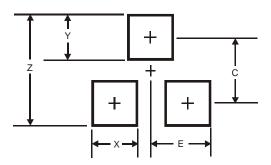
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



|     | SOT23  |         |       |  |  |  |  |  |  |
|-----|--------|---------|-------|--|--|--|--|--|--|
| Dim | Min    | Max     | Тур   |  |  |  |  |  |  |
| Α   | 0.37   | 0.51    | 0.40  |  |  |  |  |  |  |
| В   | 1.20   | 1.40    | 1.30  |  |  |  |  |  |  |
| С   | 2.30   | 2.50    | 2.40  |  |  |  |  |  |  |
| D   | 0.89   | 1.03    | 0.915 |  |  |  |  |  |  |
| F   | 0.45   | 0.60    | 0.535 |  |  |  |  |  |  |
| G   | 1.78   | 2.05    | 1.83  |  |  |  |  |  |  |
| н   | 2.80   | 3.00    | 2.90  |  |  |  |  |  |  |
| J   | 0.013  | 0.10    | 0.05  |  |  |  |  |  |  |
| К   | 0.890  | 1.00    | 0.975 |  |  |  |  |  |  |
| K1  | 0.903  | 1.10    | 1.025 |  |  |  |  |  |  |
| L   | 0.45   | 0.61    | 0.55  |  |  |  |  |  |  |
| L1  | 0.25   | 0.55    | 0.40  |  |  |  |  |  |  |
| М   | 0.085  | 0.150   | 0.110 |  |  |  |  |  |  |
| а   | 8°     |         |       |  |  |  |  |  |  |
| All | Dimens | ions in | mm    |  |  |  |  |  |  |

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z          | 2.9           |
| Х          | 0.8           |
| Y          | 0.9           |
| С          | 2.0           |
| E          | 1.35          |



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